Single Bit Uni-Directional Translator

FXLP34

Description

The FXLP34 is a single translator with two separate supply voltages: V_{CC1} for input translation voltages and V_{CC} for output translation voltages. The FXLP34 is part of **onsemi**'s Ultra Low Power (ULP) series of products. This device operates with VCC values from 1.0 V to 3.6 V, and is intended for use in portable applications that require ultra low power consumption.

The internal circuit is composed of a minimum of buffer stages, to enable ultra low dynamic power.

The FXLP34 is uniquely designed for optimized power and speed, and is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

- 1.0 V to 3.6 V V_{CC} Supply Voltage
- Converts Any Voltage (1.0 V to 3.6 V) to (1.0 V to 3.6 V)
- 4.6V Tolerant Inputs and Outputs
- t_{PD}:
 - ◆ 4 ns Typical for 3.0 V to 3.6 V V_{CC}
- Power-Off High Impedance Inputs and Outputs
- Static Drive (I_{OH}/I_{OL}):
 - ★ ±2.6 mA at 3.00 V V_{CC}
- Uses Proprietary Quiet Series Noise / EMI Reduction Circuitry
- Ultra–Small MicroPak[™] Leadless Packages
- Ultra-Low Dynamic Power
- These are Pb–Free Devices

MARKING DIAGRAM



SIP6 1.45X1.0 CASE 127EB





UDFN6 1.0X1.0, 0.35P CASE 517DP





SC-88A (SC-70 5 Lead), 1.25x2 CASE 419AC-01



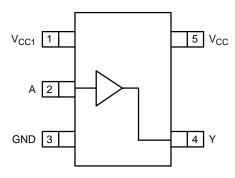
X3, X34 = Device Code
M = Assembly Operation Month

ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

1

PIN CONFIGURATION



V_{CC1} 1 1 V_{CC}

A 2 2 2 NC

GND 3 3 3 Y

Figure 1. SC70 (Top View)

Figure 2. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # SC70	Pin # MicroPak	Name	Description
1	1	Vcc1	Input Translation Voltage
2	2	А	Input
3	3	GND	Ground
4	4	Y	Output
	5	NC	No Connect
5	6	Vcc	Output Translation Voltage

TRUTH TABLE

Input	Outputs
A	Υ
L	L
Н	Н

H = Logic Level HIGH L = Logic Level Low

ABSOLUTE MAXIMUM RATINGS

Symbol	Parame	ter	Min	Max	Unit
Vcc, Vcc1	Supply Voltage	-0.5	+4.6	V	
VIN	DC Input Voltage	DC Input Voltage			V
Vout	DC Output Voltage HIGH or LOW State (Note 1)		-0.5	V _{CC} + 0.5 V	V
		V _{CC} = 0 V	-0.5	+4.6	1
lıĸ	DC Input Diode Current	V _{IN} < 0	-	-50	mA
Іок	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
		Vout > Vcc	-	+50	1
IOH/IOL	DC Output Source/Sink Current	•	-	±50	mA
Icc or Ignd	DC V _{CC} or Ground Current per Supply	Pin	_	±100	mA
Тѕтс	Storage Temperature Range		– 65	150	°C
P _D	Power Dissipation at +85°C	SC70-6	_	180	mW
		MicroPak™ <i>–</i> 6	_	130	1
		MicroPak2™-6	-	120	1
ESD	Human Body Model, JEDEC:JESD22-A114		-	4000	V
	Charge Device Model, JEDEC:JESD22	2–C101	-	2000	1

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc, Vcc1	Supply Voltage		1.0	3.6	V
VIN	Input Voltage		0	3.6	V
Vout	Output Voltage	HIGH or LOW State	0	Vcc	V
		V _{CC} = 0 V	0	3.6	
IOH/IOL	Output Current in I _{OH} /I _{OL}	V _{CC} = 3.0 to 3.6 V	-	±2.6	mA
		V _{CC} = 2.3 to 2.7 V	-	±2.1	
		V _{CC} = 1.65 to 1.95 V	-	±1.5	
		V _{CC} = 1.40 to 1.60 V	-	±1.0	
		V _{CC} = 1.10 to 1.30 V	-	±0.5	
		V _{CC} = 1.0 V	-	±20	μΑ
T _A	Operating Temperature, Free Air		-40	+85	°C
θЈА	Thermal Resistance	SC70-6	-	425	°C/W
		MicroPak-6	-	500	
		MicroPak2-6	-	560	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

^{1.} I_O Absolute Maximum Rating must be observed.

^{2.} Unused inputs must be held HIGH or LOW. They may not float.

ELECTRICAL CHARACTERISTIICS

					T _A = -	+25°C	$T_A = -40$	to 85°C	
Symbol	Parameter	Condition	V _{CC} (V)	V _{CC1} (V)	Min	Max	Min	Max	Unit
V _{IH}	HIGH		1.0 to 3.6	1.0	0.65 x V _{CCI}	-	0.65 x V _{CCI}	_	V
	Level Input			1.10 ≤ V _{CC1} ≤ 1.30	0.65 x V _{CCI}	-	0.65 x V _{CCI}	-	
	(V _{CC1})			1.40 ≤ V _{CC1} ≤ 1.60	0.65 x V _{CCI}	-	0.65 x V _{CCI}	-	
				1.65 ≤ V _{CC1} ≤ 1.95	0.65 x V _{CCI}	-	0.65 x V _{CCI}	-	
				$2.30 \le V_{CC1} \le 2.70$	1.6	_	1.6	_	
				$3.00 \le V_{CC1} \le 3.60$	2.1	-	2.1	-	
V _{IL}	LOW		1.0 to 3.6	1.0	-	0.35 x V _{CCI}	-	0.35 x V _{CCI}	V
	Level Input			$1.10 \le V_{CC1} \le 1.30$	-	0.35 x V _{CCI}	-	0.35 x V _{CCI}	
	(V _{CC1})			1.40 ≤ V _{CC1} ≤ 1.60	-	0.35 x V _{CCI}	-	0.35 x V _{CCI}	
				$1.65 \le V_{CC1} \le 1.95$	-	0.35 x V _{CCI}	-	0.35 x V _{CCI}	
				$2.30 \le V_{CC1} \le 2.70$	-	0.7	-	0.7	
				$3.00 \le V_{CC1} \le 3.60$	_	0.9	-	0.9	
V _{OH}	HIGH	$I_{OH} = -20 \mu A$	1.0	1.0 to 3.6	V _{CC} – 0.1	-	V _{CC} – 0.1	_	V
	Level Output		$1.10 \le V_{CC1} \le 1.30$		V _{CC} - 0.1	-	V _{CC} – 0.1	_	
	(V _{CC})		1.40 ≤ V _{CC1} ≤ 1.60		V _{CC} - 0.1	-	V _{CC} – 0.1	_	
			$1.65 \le V_{CC1} \le 1.95$		V _{CC} - 0.1	-	V _{CC} – 0.1	_	
			$2.30 \le V_{CC1} \le 2.70$		V _{CC} - 0.1	-	V _{CC} – 0.1	_	
			$3.00 \le V_{CC1} \le 3.60$		V _{CC} - 0.1	-	V _{CC} – 0.1	_	
		$I_{OH} = -0.5 \text{ mA}$	$1.10 \le V_{CC1} \le 1.30$	1.0 to 3.6	0.75 x V _{CC}	_	0.70 x V _{CC}	_	
		$I_{OH} = -1.0 \text{ mA}$	$1.40 \le V_{CC1} \le 1.60$	1	1.07	_	0.99	_	
		$I_{OH} = -1.5 \text{ mA}$	$1.65 \le V_{CC1} \le 1.95$	1	1.24	-	1.22	-	
		$I_{OH} = -2.1 \text{ mA}$	$2.30 \le V_{CC1} \le 2.70$	1	1.95	-	1.87	-	
		$I_{OH} = -2.6 \text{ mA}$	$3.00 \le V_{CC1} \le 3.60$	1	2.61	-	2.55	_	
V _{OL}	LOW	I _{OL} = 20 μA	1.0	1.0 to 3.6	-	0.1	-	0.1	V
	Level Output		$1.10 \le V_{CC1} \le 1.30$	1	_	0.1	-	0.1	
	(V _{CC})		$1.40 \le V_{CC1} \le 1.60$		_	0.1	-	0.1	
			$1.65 \le V_{CC1} \le 1.95$		_	0.1	-	0.1	
			$2.30 \le V_{CC1} \le 2.70$		_	0.1	-	0.1	
		$I_{OL} = 0.5 \text{ mA}$	$1.10 \le V_{CC1} \le 1.30$	1.0 to 3.6	_	0.30 x V _{CC}	-	0.30 x V _{CC}	
		I _{OL} = 1.0 mA	$1.40 \le V_{CC1} \le 1.60$		_	0.31	-	0.37	
		I _{OL} = 1.5 mA	$1.65 \le V_{CC1} \le 1.95$		_	0.31	-	0.35	
		I _{OL} = 2.1 mA	$2.30 \le V_{CC1} \le 2.70$		_	0.31	-	0.33	
		I_{OL} = 2.6 mA	$3.00 \le V_{CC1} \le 3.60$		_	0.31	-	0.33	
I _{IN}	Input Leakage Current	$0 \le V_{IN} \le 3.60$		1.0 to 3.6	-	±0.1	-	±1.0	μΑ
I _{OFF}	Power Off Leakage Current	$0 \le (V_{IN}, V_{O})$ ≤ 3.60	0	0	-	1.0	-	5.0	μΑ
Icc	Quiescent Supply Current	V _{IN} = V _{CC} or GND	1.0 to 3.6	1.0 to 3.6	-	0.9	-	5.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTIICS

				-	Γ _A = +25°(3	T _A = -40) to 85°C		
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	Figure
t _{PHL} ,	Propagation Delay	C _L = 10 pF,	1.0	_	26.0	-	_	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.0	$R_L = 1 M\Omega$	1.10 to 1.30	15.0	25.0	38.1	12.0	43.3		Figure 4
	30 ()		1.40 to 1.60	14.0	24.0	36.7	11.0	42.0		
			1.65 to 1.95	13.0	23.0	36.0	10.0	41.4		
			2.30 to 2.70	12.0	22.0	35.5	9.0	40.9		
			3.00 to 3.60	11.0	21.0	35.5	8.0	40.6		
t _{PHL} ,	Propagation Delay	C _L = 10 pF,	1.0	-	18.0	-	_	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.2	$R_L = 1 M\Omega$	1.10 to 1.30	8.0	15.0	23.2	6.0	41.0		Figure 4
			1.40 to 1.60	7.5	14.0	21.7	5.5	39.1		
			1.65 to 1.95	7.0	13.0	20.9	5.0	32.3	1	
			2.30 to 2.70	6.5	12.0	20.4	4.5	29.6		
			3.00 to 3.60	6.0	12.0	20.2	4.0	29.4		
t _{PHL} ,		$C_L = 10 \text{ pF},$	1.0	_	14.0	-	_	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.5	$R_L = 1 M\Omega$	1.10 to 1.30	5.0	11.0	16.3	4.0	20.6	1	Figure 4
	100 (17)		1.40 to 1.60	4.8	10.0	14.8	3.5	19.3		
			1.65 to 1.95	4.5	9.0	14.1	3.0	18.7	1	
			2.30 to 2.70	4.0	8.0	13.5	2.5	18.0		
			3.00 to 3.60	3.5	8.0	13.3	2.0	17.8		
t _{PHL} ,	Propagation Delay	C _L = 10 pF,	1.0	-	13.0	-	_	-		Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.8	$R_L^2 = 1 M\Omega$	1.10 to 1.30	4.0	9.0	13.5	3.0	17.5		Figure 4
			1.40 to 1.60	3.5	8.0	12.0	2.5	16.3		
			1.65 to 1.95	3.0	7.0	11.3	2.0	15.6		
			2.30 to 2.70	2.5	6.0	10.7	1.5	15.0		
			3.00 to 3.60	2.5	6.0	10.5	1.0	14.7		
t _{PHL} ,	Propagation Delay	C _L = 10 pF,	1.0	-	12.0	-	_	_	ns	Figure 3,
t _{PLH}	Output Translation V_{CC} (V) = 2.5	$R_L = 1 M\Omega$	1.10 to 1.30	3.0	7.0	10.9	2.5	14.3		Figure 4
			1.40 to 1.60	2.5	6.0	9.4	2.0	13.1		
			1.65 to 1.95	2.0	5.0	8.6	1.5	11.4		
			2.30 to 2.70	1.5	4.0	8.0	1.0	10.8		
			3.00 to 3.60	1.5	4.0	7.8	1.0	10.5	1	
t _{PHL} ,	Propagation Delay	C _L = 10 pF,	1.0	_	11.0	-	-	-	ns	Figure 3,
t _{PLH}	Output Translation $V_{CC}(V) = 3.3$	$R_L = 1 M\Omega$	1.10 to 1.30	3.0	6.0	10.1	2.0	13.8]	Figure 4
	30 ()		1.40 to 1.60	2.5	5.0	8.2	1.5	10.5]	
			1.65 to 1.95	2.0	4.0	7.4	1.0	9.9]	
			2.30 to 2.70	1.0	3.0	6.8	1.0	9.2	1	
			3.00 to 3.60	1.0	3.0	6.6	1.0	9.0		

AC ELECTRICAL CHARACTERISTIICS (continued)

					Γ _A = +25°(C	$T_A = -40$	to 85°C		
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	Figure
t _{PHL} ,	Propagation Delay	$C_L = 15 pF$,	1.0	_	28.0	-	-	-	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.0	$R_L = 1 M\Omega$	1.10 to 1.30	16.0	27.0	43.0	12.0	44.8		Figure 4
	00 ()		1.40 to 1.60	15.0	26.0	41.6	11.0	43.6		
			1.65 to 1.95	14.0	25.0	40.9	10.0	47.9		
			2.30 to 2.70	13.0	24.0	40.5	9.0	47.5		
			3.00 to 3.60	12.0	23.0	40.4	8.0	41.4		
t _{PHL} ,	Propagation Delay	$C_L = 15 pF$,	1.0	_	19.0	-	_	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.2	$R_L = 1 M\Omega$	1.10 to 1.30	9.0	16.0	24.6	8.0	43.1		Figure 4
	00 ()		1.40 to 1.60	8.5	15.0	23.1	7.5	42.2		
			1.65 to 1.95	8.0	14.0	22.4	7.0	31.4		
			2.30 to 2.70	7.5	13.0	21.8	6.5	30.7		
			3.00 to 3.60	7.0	13.0	21.6	6.0	30.5		
t _{PHL} ,	Propagation Delay	$C_L = 15 pF$,	1.0	_	15.0	_	_	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.5	$R_L = 1 M\Omega$	1.10 to 1.30	6.0	12.0	17.2	5.5	21.5		Figure 4
			1.40 to 1.60	5.8	11.0	15.7	5.0	20.3		
			1.65 to 1.95	5.5	10.0	14.9	4.5	19.6		
			2.30 to 2.70	5.0	9.0	14.3	4.0	18.9		
			3.00 to 3.60	4.5	.0	14.2	3.5	18.7		
t _{PHL} ,	Propagation Delay	$C_L = 15 pF$,	1.0	_	14.0	_	_	_	Figur	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 1.8	$R_L = 1 M\Omega$	1.10 to 1.30	5.0	8.0	14.2	5.5	18.2		Figure 4
	33 ()		1.40 to 1.60	4.5	7.0	12.7	4.0	17.0		
			1.65 to 1.95	4.0	6.0	11.9	3.5	16.3		
			2.30 to 2.70	3.5	5.0	11.3	3.0	15.7		
			3.00 to 3.60	3.5	5.0	11.2	2.5	14.4		
t _{PHL} ,	Propagation Delay	$C_L = 15 pF,$	1.0	_	12.0	-	-	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 2.5	$R_L = 1 M\Omega$	1.10 to 1.30	4.0	7.0	11.3	3.5	14.9		Figure 4
	00 ()		1.40 to 1.60	3.5	6.0	9.8	3.0	13.6		
			1.65 to 1.95	3.0	5.0	9.1	2.5	12.0		
			2.30 to 2.70	2.5	4.0	8.5	2.0	11.3]	
			3.00 to 3.60	2.5	4.0	8.3	2.0	11.1		
t _{PHL} ,	Propagation Delay C _L = 15	C _L = 15 pF,	1.0	-	11.0	_	-	_	ns	Figure 3,
t _{PLH}	Output Translation V _{CC} (V) = 3.3	$R_L = 1 M\Omega$	1.10 to 1.30	3.0	6.0	10.5	2.0	14.2	Figure 4	
	00 ()		1.40 to 1.60	2.5	5.0	8.6	1.5	11.0		
			1.65 to 1.95	2.0	4.0	7.8	1.0	10.3		
			2.30 to 2.70	1.5	3.0	7.2	1.0	9.7		
			3.00 to 3.60	1.5	3.0	7.0	1.0	9.4		<u> </u>

AC ELECTRICAL CHARACTERISTIICS (continued)

				7	A = +25°(;	$T_A = -40$	to 85°C		
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	Figure
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF},$	1.0	_	34.0	ı	_	_	ns	Figure 3,
t _{PLH}	Output Translation $V_{CC}(V) = 1.0$	$R_L = 1 M\Omega$	1.10 to 1.30	19.0	32.0	48.6	15.0	55.5		Figure 4
			1.40 to 1.60	18.0	31.0	47.1	14.0	52.3		
			1.65 to 1.95	17.0	30.0	46.4	13.0	50.6		
			2.30 to 2.70	16.0	29.0	45.9	12.0	49.2		
			3.00 to 3.60	15.0	28.0	45.8	10.0	49.1		
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF},$	1.0	_	22.0	-	-	_	ns	Figure 3,
^t PLH	Output Translation $V_{CC}(V) = 1.2$	$R_L = 1 M\Omega$	1.10 to 1.30	11.0	19.0	29.0	10.0	46.5		Figure 4
	00 ()		1.40 to 1.60	10.0	18.0	27.5	9.0	42.6		
			1.65 to 1.95	9.0	17.0	26.7	8.0	36.7		
			2.30 to 2.70	8.5	16.0	26.1	7.0	36.0		
			3.00 to 3.60	8.0	16.0	26.0	6.0	35.9		
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF},$	1.0	_	16.0	_	_	_	ns	Figure 3,
t _{PLH}	Output Translation V_{CC} (V) = 1.5	$R_L = 1 M\Omega$	1.10 to 1.30	6.0	13.0	19.8	5.5	25.3		Figure 4
	00 ()		1.40 to 1.60	5.8	12.0	18.3	5.0	23.0		
			1.65 to 1.95	5.5	11.0	17.6	4.5	22.4		
			2.30 to 2.70	5.0	10.0	17.0	4.0	21.7		
			3.00 to 3.60	4.5	9.0	16.8	3.5	21.5		
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF},$	1.0	_	15.0	_	_	_	ns	Figure 3,
t _{PLH}	Output Translation $V_{CC}(V) = 1.8$	$R_L = 1 M\Omega$	1.10 to 1.30	5.0	11.0	16.2	5.5	20.4		Figure 4
	30 ()		1.40 to 1.60	4.5	10.0	14.7	4.0	19.2		
			1.65 to 1.95	4.0	9.0	13.9	3.5	18.5		
			2.30 to 2.70	3.5	8.0	13.3	3.0	17.9		
			3.00 to 3.60	3.5	8.0	13.1	2.5	17.6		
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF},$	1.0	_	13.0	-	-	_	ns	Figure 3,
t _{PLH}	Output Translation $V_{CC}(V) = 2.5$	$R_L = 1 M\Omega$	1.10 to 1.30	4.0	8.0	12.7	3.5	15.9		Figure 4
	60 ()		1.40 to 1.60	3.5	7.0	11.2	3.0	14.3		
			1.65 to 1.95	3.0	6.0	10.5	2.5	13.6		
			2.30 to 2.70	2.5	5.0	9.9	2.0	12.8		
			3.00 to 3.60	2.5	5.0	9.7	2.0	12.5		
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF},$	1.0	_	12.0	_	-	_	ns	Figure 3,
t _{PLH}	Output Translation $V_{CC}(V) = 3.3$	$R_L = 1 M\Omega$	1.10 to 1.30	3.0	8.0	11.7	2.0	15.0		Figure 4
	100(1) 0.0		1.40 to 1.60	2.5	7.0	9.8	1.5	12.2		
			1.65 to 1.95	2.0	6.0	8.9	1.0	11.5		
			2.30 to 2.70	1.5	5.0	8.3	1.0	10.7		
			3.00 to 3.60	1.5	5.0	8.1	1.0	10.4		

CAPACITANCE

			V _{CC} /	T _A = +25°C	
Symbol	Parameter	Conditions	V _{CC1} (V)	Тур	Unit
C _{IN}	Input Capacitance			2	pF
C _{I/O}	Input/Output Capacitance			4	pF
C _{PD}	Power Dissipation Capacitance	$V_1 = 0 \text{ V or } V_{CC1}, f = 10 \text{ MHz}, V_{CC} / V_{CC1} = 3.6 \text{ V}$	1.0 to 3.60	8	pF

Translator Power-up Sequence Recommendations

To ensure that the system does not experience unnecessary I_{CC} current draw, bus contention, or oscillations during power—up; adhere to the following guidelines. This device is designed with the output pin(s) supplied by V_{CC} and the input pin(s) supplied by V_{CC1} . The first recommendation is to begin by powering up the input side of the device with V_{CC1} . The Input pin(s) should be ramped with or ahead of V_{CC1} or held LOW. This guards against bus contentions and oscillations as all inputs and the

input V_{CC1} are powered at the same time. The output V_{CC} can then be powered to the target voltage level to which the device will translate. The output pin(s) then translate to logic levels dictated by the output V_{CC} levels.

Upon completion of these steps, the device can be configured for the desired operation. Following these steps helps prevent possible damage to the translator device as well as other system components

AC Loadings and Waveforms

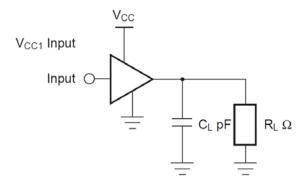


Figure 3. AC Test Circuit

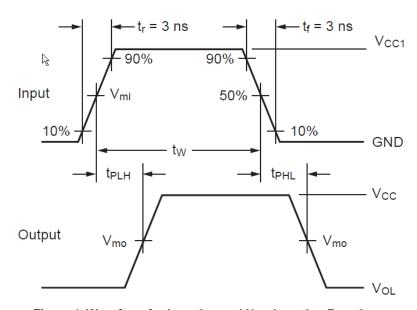


Figure 4. Waveform for Inverting and Non-Inverting Functions

Table 1. AC LOAD TABLE

	V _{CC}							
Symbol	3.3 V ±0.3 V	2.5 V ±0.2 V	1.8 V ±0.15 V	1.5 V ±0.10 V	1.2 V ±0.10 V	1.0 V		
V _{mi}	1.5V	V _{CC1} /2						
V _{mo}	1.5V	V _{CC} /2						

ORDERING INFORMATION

Part Number	Top Mark	Package Type	Shipping [†]
FXLP34P5X	X34	5-Lead SC70, EIAJ SC-88a, 1.25 mm Wide (Pb-Free)	3000 / Tape & Reel
FXLP34L6X	Х3	SIP6, 6-Lead MicroPak, 1.00 mm Wide (Pb-Free)	5000 / Tape & Reel
FXLP34FHX	Х3	UDFN6, 6-Lead, MicroPak2, 1x1 mm Body, .35 mm Pitch (Pb-Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak and MicroPak2 are trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries.



DATE 31 AUG 2016



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

 - OTHER LINE IN THE MARK CODE LAYOUT.

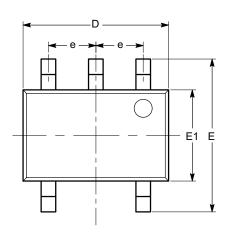
DOCUMENT NUMBER:	98AON13590G	Electronic versions are uncontrolled except when accessed directly from the Document Reposi Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION:	SIP6 1.45X1.0		PAGE 1 OF 1				

ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

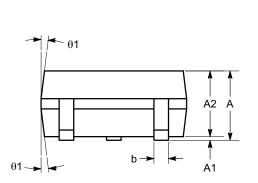


SC-88A (SC-70 5 Lead), 1.25x2 CASE 419AC-01 ISSUE A

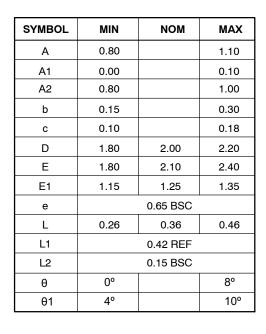
DATE 29 JUN 2010

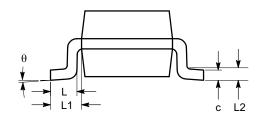


TOP VIEW



SIDE VIEW





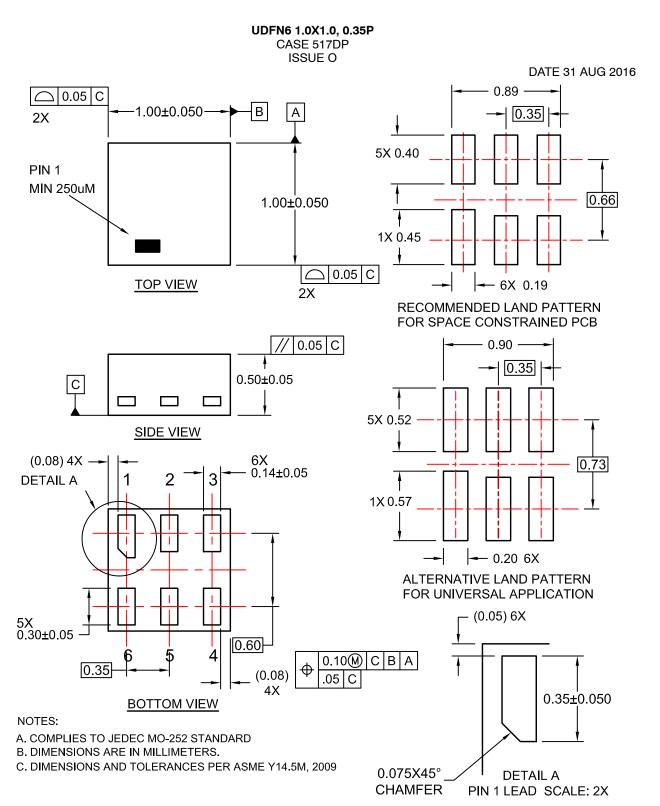
END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-203.

DOCUMENT NUMBER:	98AON34260E	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	' '
DESCRIPTION:	SC-88A (SC-70 5 L FAD).	1.25X2	PAGE 1 OF 1

ON Semiconductor and at a trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



DOCUMENT NUMBER:	98AON13593G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6 1.0X1.0, 0.35P		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales